



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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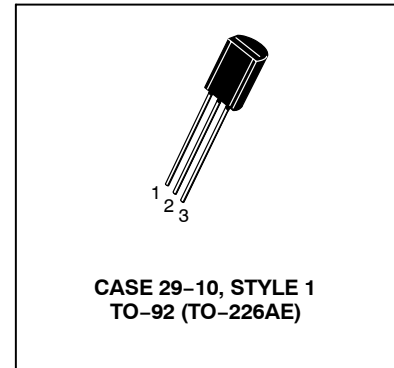
One Watt Darlington Transistors

PNP Silicon

MPSW63
MPSW64*

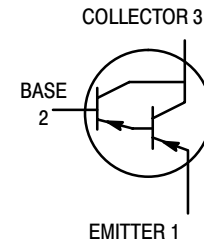
*ON Semiconductor Preferred Device

- These devices are available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at www.onsemi.com for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative.



MAXIMUM RATINGS

Rating	Symbol	MPSW63 MPSW64	Unit
Collector – Emitter Voltage	V_{CES}	-30	Vdc
Collector – Base Voltage	V_{CBO}	-30	Vdc
Emitter – Base Voltage	V_{EBO}	-10	Vdc
Collector Current — Continuous	I_C	-500	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0 8.0	Watt mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	2.5 20	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	50	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector – Emitter Breakdown Voltage ($I_C = -100 \mu\text{Adc}, V_{BE} = 0$)	$V_{(BR)CES}$	-30	—	Vdc
Collector Cutoff Current ($V_{CB} = -30 \text{Vdc}, I_E = 0$)	I_{CBO}	—	-100	nAdc
Emitter Cutoff Current ($V_{EB} = -10 \text{Vdc}, I_C = 0$)	I_{EBO}	—	-100	nAdc

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

MPSW63 MPSW64

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS⁽¹⁾				
DC Current Gain ($I_C = -10\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)	h_{FE}	5,000	—	—
	MPSW63 MPSW64	10,000	—	—
($I_C = -100\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)	MPSW63	10,000	—	—
	MPSW64	20,000	—	—
Collector–Emitter Saturation Voltage ($I_C = -100\text{ mAdc}$, $I_B = -0.1\text{ mAdc}$)	$V_{CE(sat)}$	—	-1.5	Vdc
Base–Emitter On Voltage ($I_C = -100\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)	$V_{BE(on)}$	—	-2.0	Vdc

SMALL-SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ⁽²⁾ ($I_C = -10\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$, $f = 100\text{ MHz}$)	f_T	125	—	MHz
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1. Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$.
2. $f_T = |h_{fe}| \cdot f_{test}$.

TYPICAL ELECTRICAL CHARACTERISTICS

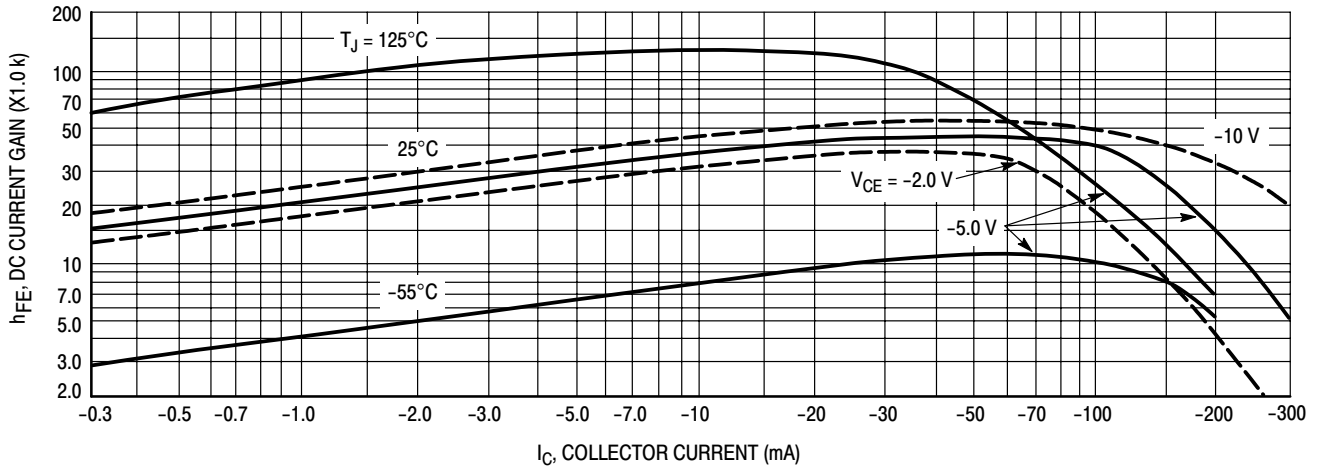


Figure 1. DC Current Gain

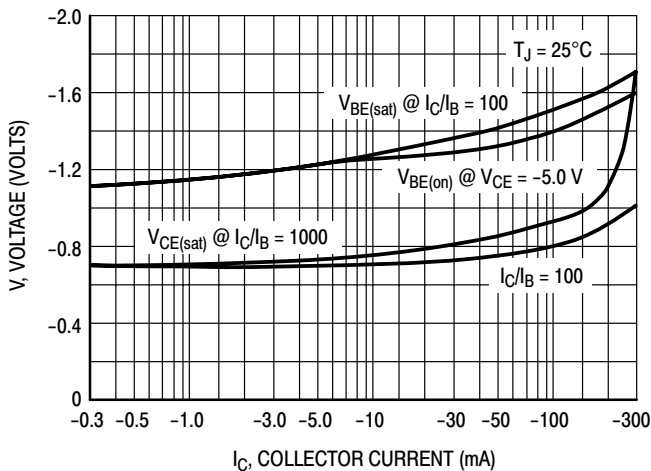


Figure 2. "ON" Voltage

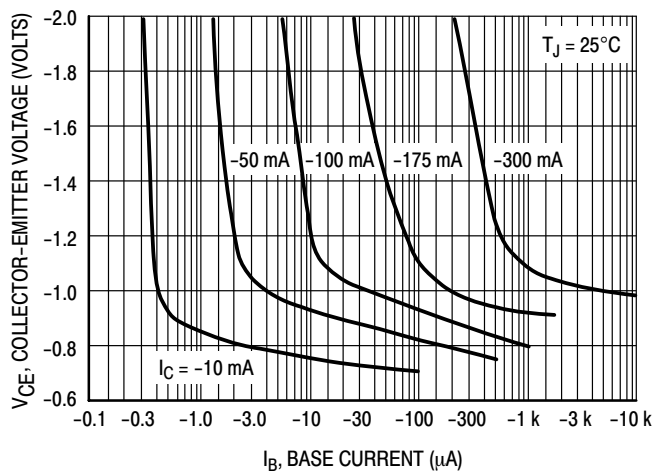


Figure 3. Collector Saturation Region

MPSW63 MPSW64

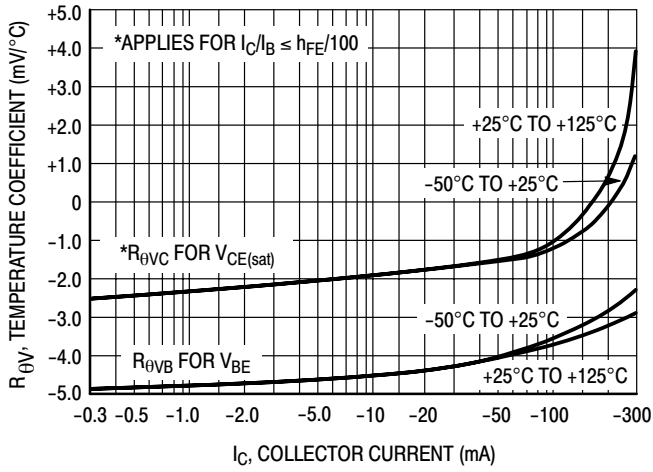


Figure 4. Temperature Coefficients

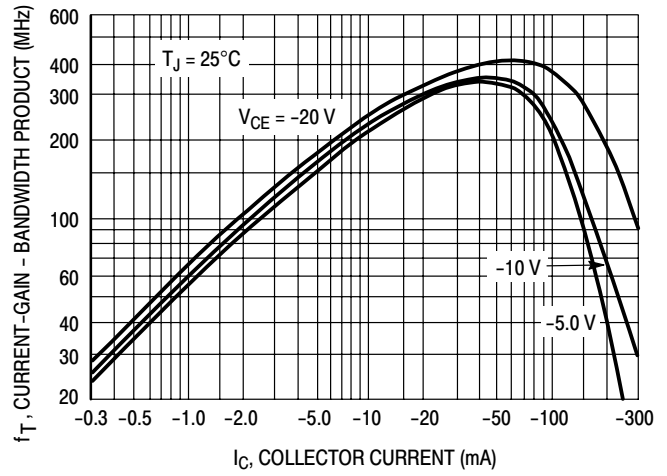


Figure 5. Current-Gain — Bandwidth Product

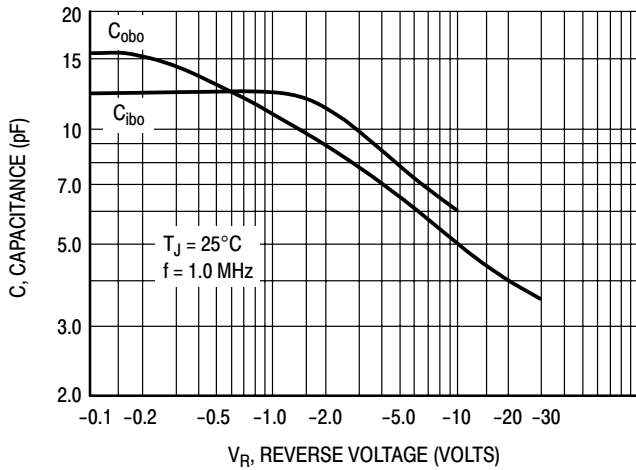


Figure 6. Capacitance

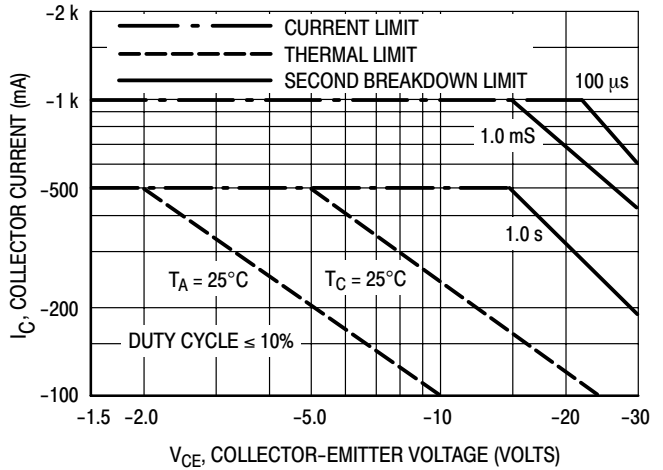
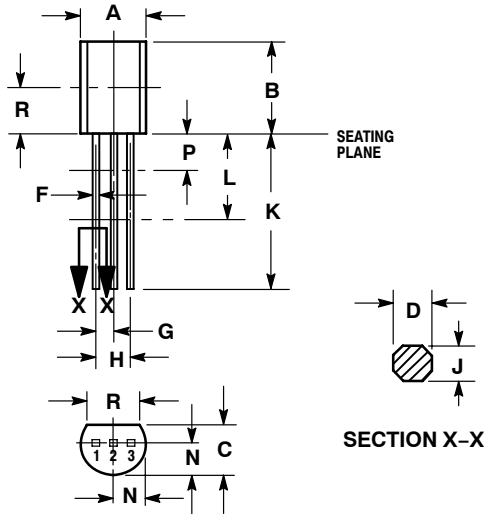


Figure 7. Active Region, Safe Operating Area

MPSW63 MPSW64

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-10 ISSUE AL




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.021	0.457	0.533
F	0.016	0.019	0.407	0.482
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---

TYPE 1:

1. EMITTER
2. BASE
3. COLLECTOR

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